# Darlington Power Transistor





## **Description**

The is a silicon epitaxial-base NPN power transistors in monolithic Darlington configuration and are mounted in JEDEC TO-3 metal case. They are intended for use in power linear and switching applications.

## **Absolute Maximum Ratings**

Parameter	Symbol	Values	Unit	
Collector-Base Voltage (IE = 0)	Vсво	00		
Collector-Emitter Voltage (IB = 0)	VCEO	80	V	
Emitter-Base Voltage (Ic = 0)	VEBO	5	]	
Collector Current	Ic	10	^	
Base Current	Ів	0.2	_ A	
Total Dissipation at Tc ≤25°C	Ртот	150	W	
Storage Temperature	Тѕтс	-65 to +200	°C	
Maximum Operating Junction Temperature	TJ	200		

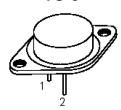
## Electrical Characteristics (TCASE = 25°C unless otherwise specified)

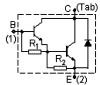
Parameter	Test Conditions	Symbol	Min.	Max.	Unit
Collector Cut-off Current (R <sub>BE</sub> = 1kΩ)	Vce = 80V Tcase = 150°C Vce = 80V	Icer	-	1 5	μA
Collector Cut-off Current (IB = 0)	VCE = 30V VCE = 40V	ICEO	-	1 1	
Emitter Cut-off Current (Ic = 0)	V <sub>EB</sub> = 5V	ІЕВО	-	2	-
Collector-Emitter Sustaining Voltage (I <sub>B</sub> = 0)	Ic = 100mA	VCEO (sus)*	80	-	
Collector-Emitter Saturation Voltage	Ic = 5A IB = 20mA Ic = 10A IB = 50mA	VCE (SAT)*	-	2 4	V
Base-Emitter Voltage	Ic = 5A VcE = 3V	V <sub>BE</sub> *	-	3	
DC Current Gain	Ic = 5A VcE = 3V	hfe*	1,000	-	-

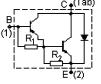
<sup>\*</sup>Pulsed : Pulse Duration = 300µs, Duty Cycle 1.5%

#### **TO-3**

## **Internal Schematic Diagram**







R<sub>1</sub>Typical = 10 KΩ

 $R_2$ Typical = 150  $\Omega$ 

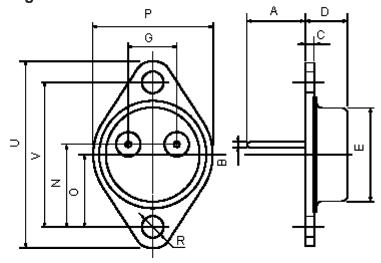
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### **Diagram**



**TO-3 Mechanical Data** 

Dimensions	Minimum	Maximum
А	11 (0.433)	13.1 (0.516)
В	0.97 (0.038)	1.15 (0.045)
С	1.5 (0.59)	1.65 (0.065)
D	8.32 (0.327)	8.92 (0.351)
E	19 (0.748)	20 (0.787)
G	10.7 (0.421)	11.1 (0.437)
N	16.5 (0.649)	17.2 (0.677)
Р	25 (0.984)	26 (1.023)
R	4 (0.157)	4.09 (0.161)
U	38.5 (1.515)	39.3 (1.547)
V	30 (1.187)	30.3 (1.193)

Dimensions: Millimetres (Inches)

#### **Part Number Table**

Description	Part Number		
Darlington Transistor, TO-3	MJ3001		

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